Molecular depth profiling directly on a rat brain tissue section using fullerene and bismuth cluster ion beams



Delphine Debois, Alain Brunelle and Olivier Laprévote

Institut de Chimie des Substances Naturelles, CNRS, 91198 Gif-sur-Yvette, France



Abstract

The capabilities of time of flight secondary ion mass spectrometry (TOF-SIMS) have been recently greatly improved with the arrival in this field of polyatomic ion sources [1,2]. This technique is now able to map at the micron scale intact organic molecules in a range of a thousand Daltons or more, at the surface of tissue samples, and many biomedical applications are expected. Nevertheless, this remains a surface analysis technique, and three-dimensional information on the molecular composition of the sample could not be obtained due to the damage undergone by the organic molecules during their irradiation. The situation changed slightly with the low damage and low penetration depth of the Cen fullerene ion beams. Several recent studies have shown the possibility of organic molecular depth profiling using this kind of beams onto model samples [3]. This possibility has been tried out directly onto a rat brain tissue section, which is the most commonly used biological tissue model in TOF-SIMS imaging method developments. The tissue surface has been sputtered with a 10 keV energy fullerene ion beam. and surface analyses were performed with a 25 keV Bi3+ ion beam at regular time intervals. The total depth which was analyzed was more than two microns, with total primary ion doses of more than 10¹⁶ ions.cm⁻². Although not in contradiction with results previously published but with much lower doses, it is found that the molecular damage remains too large, thus making molecular imaging very difficult at such a scale. In addition, most of the lipids, which are usually the main observable molecules in TOF-SIMS, are found to be concentrated close to the sample surface in the first hundreds of nanometers [4].

Materials and methods:

Experiments performed with a TOF-SIMS IV (Ion-Tof GmbH, Münster, Allemagne) time-of-flight mass spectrometer, located in Tascon GmbH company (Münster, Germany) and equipped with the two following primary ion sources:

- •A bismuth liquid metal ion source: Bi3+ ions are selected. •A fullerene ion source, from which Ceo+ ions are selected
- The experiments are performed as follows:
- 1 sec irradiations with C_{en}⁺ at 10 keV (2nA) over 300x300 μm²; 2.8x10¹³ ions.cm⁻² each irradiation,

•Followed by surface analysis with Bio* 25 keV (0.1 pA @ 200 usec) over 110x110 um², 1.5x10¹⁰ ions.cm⁻² at each analysis step

The total C60+ fluence is several 1016 ions.cm-2.

Video images of the

300x300 µm²

sputtered area at the

edge of the corpus

callosum; the green

square corresponds

to the 100x100 µm²

area analyzed by Bi.4

Irradiations located at the edge of the corpus callosum at the surface of a rat brain tisssue section (15µm) deposited onto a stainless steel plate.

The total sputtered depth is measured after the irradiation with a KLA Tencor profilometer (Surface Profilometer - Alpha Step 500, précision ~1.5 %).

Experimental results: images



lon images, total (sum along the irradiation) and recorded at the beginning in the middle and at the end of the irradiation

Definitions:

In SIMS studies, projectiles (primary ions) penetrate into the bulk for only several hundreds of Ångströms. The solid is damaged along this depth, because projectiles are slowed down by successive elastic collisions with atoms of the sample. Those atoms are displaced and molecules are destroyed

Secondary ions originate only from the first 50-100 Å [5].



References:

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The experiment:

Dual beam depth profiling: 1. C₆₀ beam to sputter with a limited damage 2. Bi3+ beam to analyse with a good efficiency



Simulations:

C₆₀

Bi. 8.3 keV/atom 166.6 eV/atom

Simulations performed with SRIM software (www.srim.org) of the penetration of a bismuth ion, element of a Bia cluster, and of a carbon ion, element of a C₆₀ cluster, into adipose tissue. A fullerene ion, which is very efficient in sputtering, has a much lower penetration depth than a bismuth ion. Thus the damage is reduced below the surface.

C ₆₀	Bi ₃
166.6	8333
10	25
485	229
22	212
	C ₆₀ 166.6 10 485 22

Experimental results: damage cross sections

50-100 Å

50-100 Å

50-100



Conclusion:

•Although the damage cross section is lower with C_{s0} ions than with cluster of heavy ions such as bismuth clusters, and although the penetration depth is much smaller with Cen than with Bismuth (22 Å instead of 212 Å), the damage remains important and the secondary ion yields undergo an important decrease during the sputtering process.

•Two different regimes are revealed by the irradiations: at the beginning, and up to a fluence of 2.8x10¹⁵ ions.cm⁻², the secondary ion yields decrease ~10 times faster than above this value

•Nevertheless the damage measured during the early beginning of the irradiation is not in contradiction with results obtained onto model layers in the literature

•It seems that most of the lipids might have been concentrated at the surface, in a depth estimated to ~200-300 nm. This can be in agreement with the results obtained by Siövall et al, who concluded that such a lipid migration could occur during the reheating of the freezed sections.

•Below the lipid-concentrated layers, the yields are too low to provide images with enough count rates.

Although C_{so} ion beams provide reduced damage and high sputtering rates, depth profiling over several microns in a tissue section remains a challenge.

Alain.Brunelle@icsn.cnrs-aif.fr